

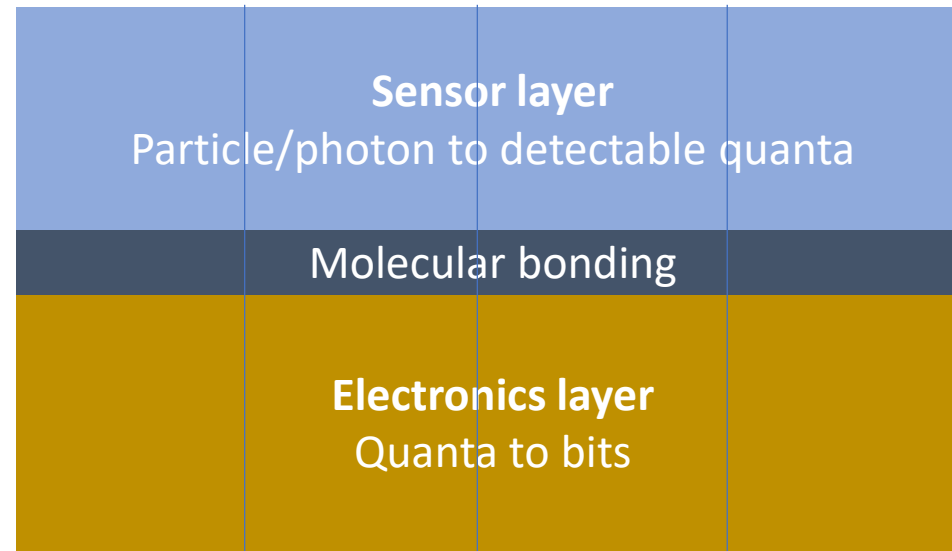
# Aim of the workshop

- 1) Learn about each other's work
- 2) Identify synergies:
  - 1) design/simulation (e.g. TCAD, Silvaco, ANSYS, ...)
  - 2) Fabrication (TSMC, DALSA, FBK, Hamamatsu,...)
  - 3) Characterization
- 3) Discuss implementation strategies
  - 1) How to avoid being sub-critical? Aka great idea but fail to implement
  - 2) How to start and get funding at low "technology readiness level"?
  - 3) How to foster emergence of "Canadian technology"?
- 4) Working together?

## Switching to my personal interest

# 3D integrated digital technology

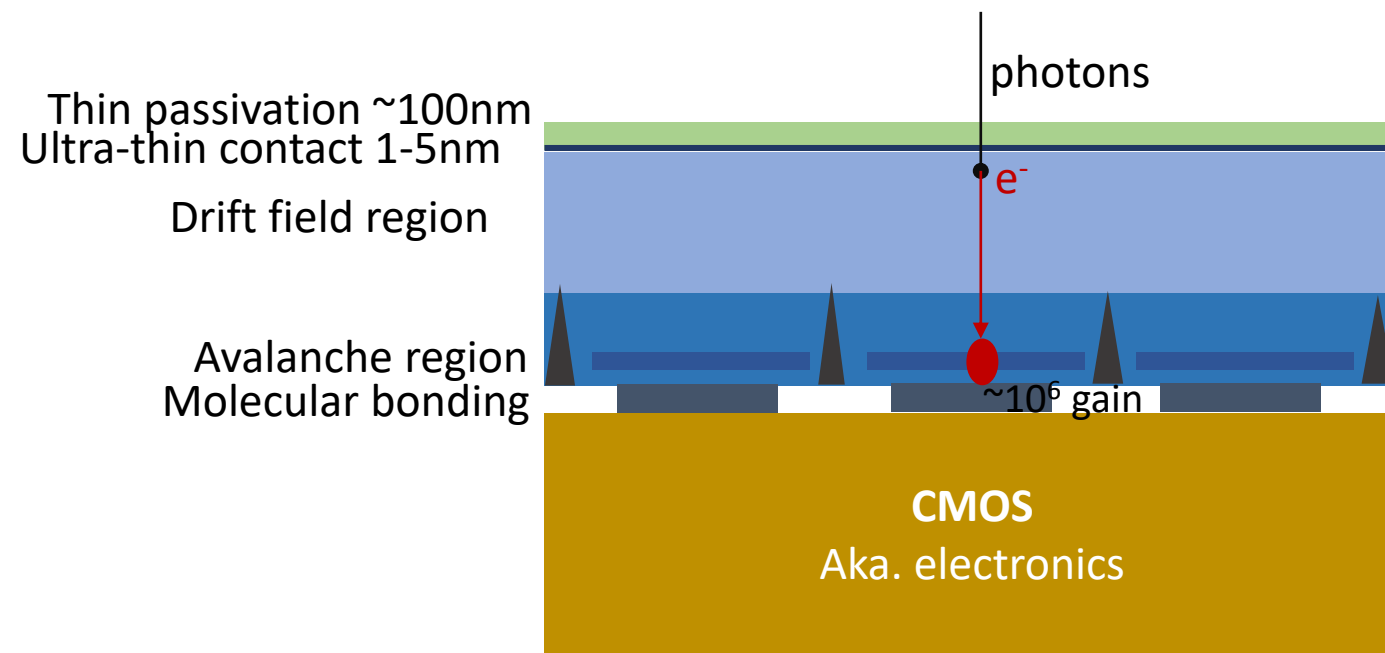
- Aim: measure charged particle and photon position & time within a single package
- Solution: 3D integration
- Technology available at Teledyne-DALSA + Sherbrooke



# 4Dimension Digital Detector, 4D<sup>3</sup> concept

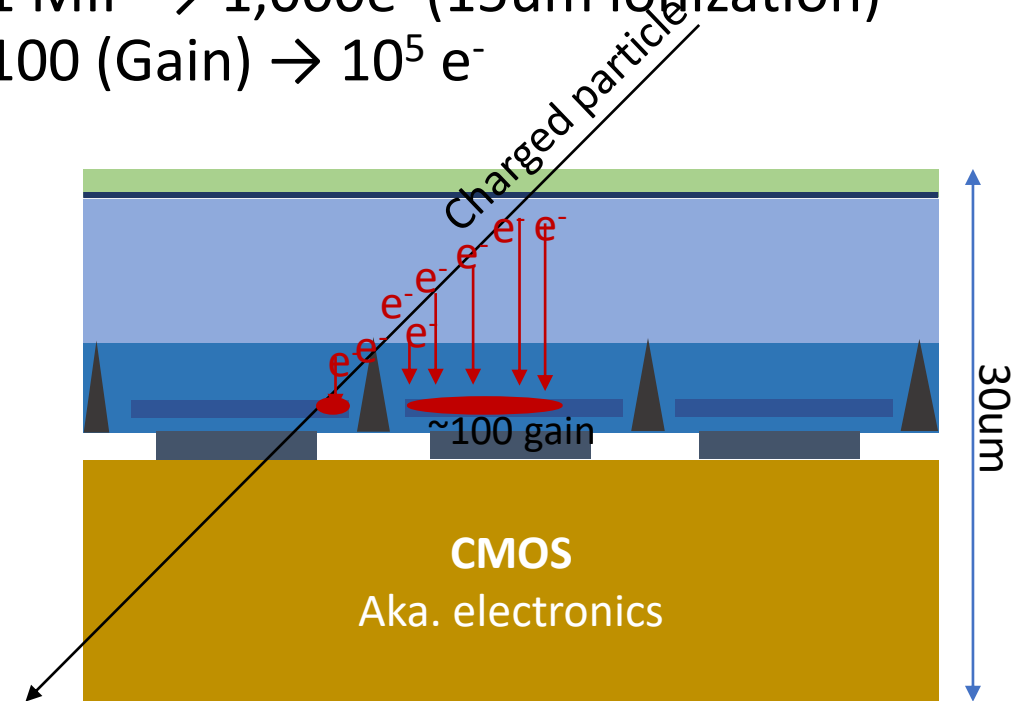
- Single Photon Avalanche Diode

- 1 photon  $\rightarrow 1e^- * 10^6$  (Gain)  $\rightarrow 10^6 e^-$



- Low Gain Avalanche Diode

- 1 MIP  $\rightarrow 1,000e^-$  (15um ionization) \* 100 (Gain)  $\rightarrow 10^5 e^-$



Signal close enough to be handled by similar electronics

Made in Canada technology: Sensor layer and 3D integration could be done at Teledyne-DALSA (Bromont, QC)

# Other configurations

- ~5keV electron detection for hybrid photo-detector (JP Yanez, Alberta)
- Thick (300-500um) for direct dark matter detection with Geiger-mode and linear gain (with P. Agnes and J. Monroe, from RHUL, UK)
- ?Heavy ionizing particle for nuclear physics?

# Electronics + information management

- “Analog” side
  - 1 comparator per diode (pixel)
  - Possibly 2 for time over threshold
- Digital. Tailor to needs. Possible configurations:
  - Blue single photon sensor + high speed TDC (10ps) + coarse position (1-5mm) [PET, plastic scintillator,..]
  - VUV/blue single photon sensor + low speed TDC (1ns) + coarse position (1-5mm) [ARGO, nEXO]
  - Charged particle sensor + high speed TDC (10ps) + fine position (<100um) + rad hard [collider]

# Making this happen... challenges

- Sensor development
  - Currently only front side configuration exists. Need to move to Back side
  - <350nm wavelength detection require very shallow doping
  - Radiation hardness
- Molecular bonding development
  - Available at DALSA but not used yet
- CMOS
  - Sherbrooke has produced 2 flavors both with coarse position information: high speed/high power, and low speed/low power
  - Radiation hardness

**Need \$\$\$ and possibly/probably a collaboration structure**